

SEMICONDUCTOR

500 mW LL-34 Hermetically Sealed Glass Fast Switching Diodes



Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
P _D	Power Dissipation	500	mW
T _{STG}	Storage Temperature Range	-65 to +150	°C
TJ	Operating Junction Temperature	+150	°C
W _{IV}	Working Inverse Voltage	75	V
lo	Average Rectified Current	150	mA
I _{FM}	Non-repetitive Peak Forward Current	450	mA
I _{FSURGE}	Peak Forward Surge Current (Pulse Width = 1.0 µsecond)	2	А

These ratings are limiting values above which the serviceability of the diode may be impaired.

DEVICE MARKING DIAGRAM



Cathode Band Color : Black

Specification Features:

- Fast Switching Device (T_{RR} < 4.0 nS)
- LL-34 (Mini-MELF) Package
- Surface Device Type Mounting
- Hermetically Sealed Glass
- Compression Bonded Construction
- All External Surfaces Are Corrosion Resistant And Terminals Are Readily Solderable
- RoHS Compliant
- Matte Tin (Sn) Terminal Finish
- Color band Indicates Negative Polarity



ELECTRICAL SYMBOL

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter		Test Condition	Limits		Unit
			rest condition	Min	Max	UIIIL
Ву	Breakdown Voltage		I _R =100μA	100		Volta
			I _R =5µA	75		Volts
I _R	Reverse Leakage Curre	nt	V _R =20V		25	nA
			V _R =75V		5	μA
V _F	Forward Voltage	TCLL4448, TCLL914B	I _F =5mA	0.62	0.72	
		TCLL4148	I _F =10mA		1.0	Volts
		TCLL4448, TCLL914B	I _F =100mA		1.0	
T _{RR}	Reverse Recovery Time		I _F =10mA, V _R =6V			
			R _L =100Ω		4	nS
			I _{RR} =1mA			
С	Capacitance		V _R =0V, f=1M _{HZ}		4	pF

Number: DB-055 Jan 2011 / H



Typical Characteristics

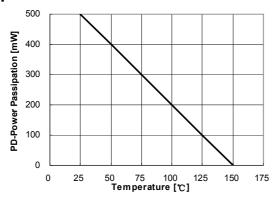


Figure 1. Power Dissipation vs Ambient Temperature Valid provided leads at a distance of 0.8mm from case are kept at ambient temperature

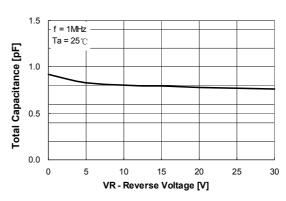


Figure 2. Total Capacitance

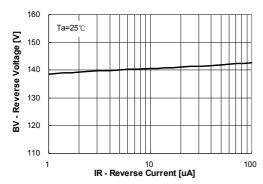


Figure 3. Reverse Voltage vs Reverse Current BV – 1.0uA to 100uA

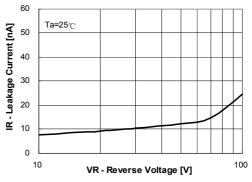


Figure 4. Reverse Current vs Reverse Voltage IR – 10V to 100V

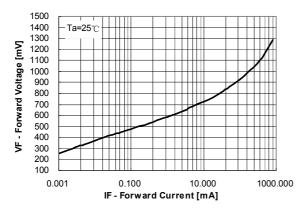


Figure 5. Forward Voltage vs Forward Current VF – 0.001mA to 800mA

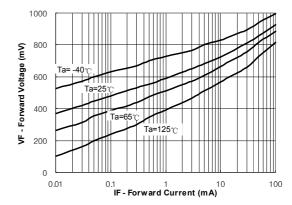


Figure 6. Forward Voltage vs Ambient Temperature VF – 0.01mA to 100mA (-40 to +125 Deg C)





Package Outline

Package	Case Outline					
	← B →	DIM	LL-34			
			Millimeters		Inches	
LL34	A	-	Min	Max	Min	Max
LLOT		Α	3.30	3.60	0.130	0.142
	<u> </u>	В	1.40	1.50	0.055	0.059
	<u> </u>	С	0.35	0.50	0.014	0.020

Notes:

- All dimensions are within DO213AC JEDEC standard.
 LL-34 polarity denoted by cathode band.

Number: DB-055 Jan 2011 / H





NOTICE

The information presented in this document is for reference only. Tak Cheong reserves the right to make changes without notice for the specification of the products displayed herein.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Tak Cheong Semiconductor Co., Ltd., or anyone on its behalf, assumes no responsibility or liability for any damagers resulting from such improper use of sale.

This publication supersedes & replaces all information reviously supplied. For additional information, please visit our website http://www.takcheong.com, or consult your nearest Tak Cheong's sales office for further assistance.

Number: DB-100 April 14, 2008 / A